

MOSFETs Silicon N-channel MOS (U-MOSX-H)

TK5R0A15Q5

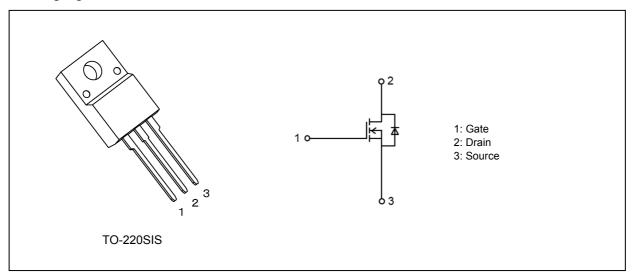
1. Applications

- High-Efficiency DC-DC Converters
- · Switching Voltage Regulators
- · Motor Drivers

2. Features

- (1) Fast reverse recovery time: $t_{rr} = 52 \text{ ns (typ.)}$
- (2) Small reverse recovery charge : $Q_{rr} = 55 \text{ nC (typ.)}$
- (3) Small gate charge: $Q_{SW} = 26 \text{ nC (typ.)}$
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 4.3 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (5) Low leakage current: $I_{DSS} = 10 \mu A (max) (V_{DS} = 150 \text{ V})$
- (6) Enhancement mode: V_{th} = 3.1 to 4.5 V (V_{DS} = 10 V, I_{D} = 2.2 mA)

3. Packaging and Internal Circuit





4. Absolute Maximum Ratings (Note) (Ta = 25 °C unless otherwise specified)

Characteristics	Symbol	Rating	Unit		
Drain-source voltage			V_{DSS}	150	V
Gate-source voltage			V _{GSS}	±20	
Drain current (DC)	(T _c = 25 °C)	(Note 1)	Ι _D	76	Α
Drain current (DC)	(Silicon limit)	(Note 1), (Note 2)	Ι _D	76	
Drain current (pulsed)	(t = 100 μs)	(Note 1)	I _{DP}	480	
Power dissipation	(T _c = 25 °C)		P_{D}	53	W
Single-pulse avalanche energy		(Note 3)	E _{AS}	136	mJ
Single-pulse avalanche current		(Note 3)	I _{AS}	76	Α
Channel temperature			T _{ch}	175	°C
Storage temperature			T _{stg}	-55 to 175	
Isolation voltage (RMS)	(t = 1.0 s)		V _{ISO(RMS)}	2000	V
Mounting torque			TOR	0.6	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics			Max	Unit
Channel-to-case thermal resistance	(T _c = 25 °C)	R _{th(ch-c)}	2.78	°C/W
Channel-to-ambient thermal resistance	(T _a = 25 °C)	R _{th(ch-a)}	62.5	

Note 1: Ensure that the channel temperature does not exceed 175 °C.

Note 2: Limited by silicon chip capability.

Note 3: V_{DD} = 100 V, T_{ch} = 25 °C (initial), L = 23 μ H, I_{AS} = 76 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±0.1	μА
Drain cut-off current	I _{DSS}	V _{DS} = 150 V, V _{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	150			V
Drain-source breakdown voltage (Note 4)	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	130	_	_	
Gate threshold voltage	V_{th}	V _{DS} = 10 V, I _D = 2.2 mA	3.1	_	4.5	
Drain-source on-resistance	R _{DS(ON)}	$V_{GS} = 8 \text{ V}, I_D = 38 \text{ A}$	_	4.5	6	mΩ
		V _{GS} = 10 V, I _D = 38 A	_	4.3	5	

Note 4: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 75 V, V _{GS} = 0 V, f = 1 MHz	_	7820	_	pF
Reverse transfer capacitance	C _{rss}		_	50	_	
Output capacitance	C _{oss}		_	1540	_	
Gate resistance	r _g	_	_	1.9	2.9	Ω
Switching time (rise time)	t _r	See Fig. 6.2.1	_	62	_	ns
Switching time (turn-on time)	t _{on}		_	95	_	
Switching time (fall time)	t _f		_	57	_	
Switching time (turn-off time)	t _{off}		_	130	_	

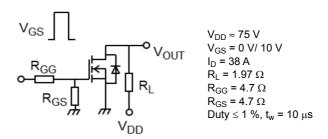


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Q_g	$V_{DD} \approx 75 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 38 \text{ A}$	_	96	_	nC
gate-drain)		$V_{DD} \approx 75 \text{ V}, V_{GS} = 8 \text{ V}, I_D = 38 \text{ A}$	_	78	_	
Gate-source charge 1	Q _{gs1}	$V_{DD} \approx 75 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 38 \text{ A}$	_	44	_	
Gate-drain charge	Q_{gd}		_	11.6	_	
Gate switch charge	Q_{SW}		_	26	_	
Output charge	Q _{oss}	V _{DS} = 75 V, V _{GS} = 0 V, f = 1 MHz	_	190	_	



6.4. Source-Drain Characteristics (T_a = 25 °C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed)	(Note 5)	I _{DRP}	t = 100 μs	_	_	480	Α
Diode forward voltage		V_{DSF}	I _{DR} = 38 A, V _{GS} = 0 V	_	_	-1.2	V
Reverse recovery time	(Note 6)	t _{rr}	I _{DR} = 19 A, V _{GS} = 0 V,	_	52	78	ns
Reverse recovery charge	(Note 6)	Q_{rr}	-dI _{DR} /dt = 100 A/μs		55	125	nC

Note 5: Ensure that the channel temperature does not exceed 175 °C.

Note 6: Defined by design.

7. Marking (Note)

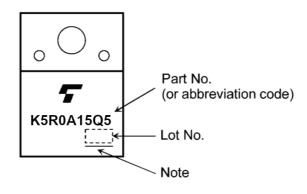


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

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8. Characteristics Curves (Note)

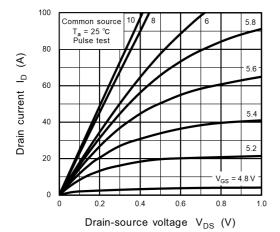


Fig. 8.1 $I_D - V_{DS}$

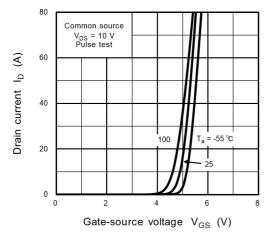


Fig. 8.3 ID - VGS

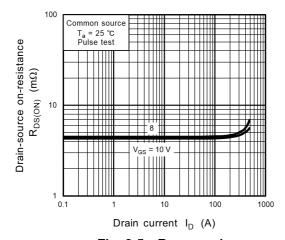


Fig. 8.5 R_{DS(ON)} - I_D

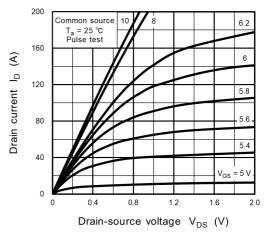


Fig. 8.2 I_D - V_{DS}

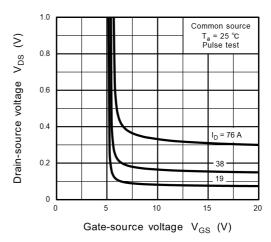


Fig. 8.4 V_{DS} - V_{GS}

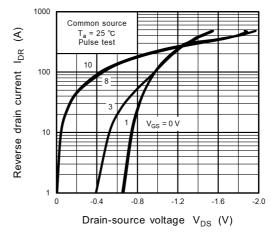


Fig. 8.6 IDR - VDS



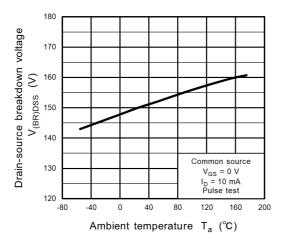


Fig. 8.7 V_{(BR)DSS} - T_a

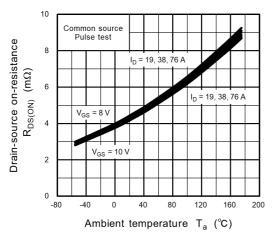


Fig. 8.9 R_{DS(ON)} - T_a

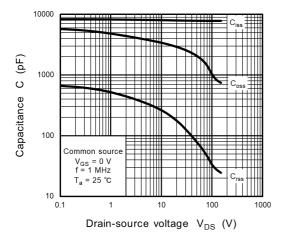


Fig. 8.11 Capacitance - V_{DS}

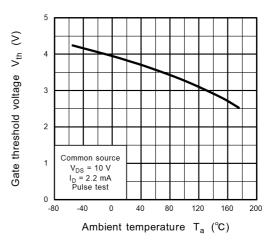


Fig. 8.8 V_{th} - T_a

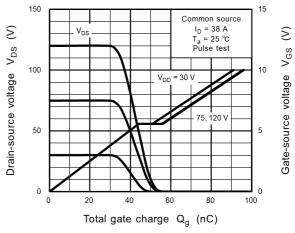


Fig. 8.10 Dynamic Input/Output Characteristics

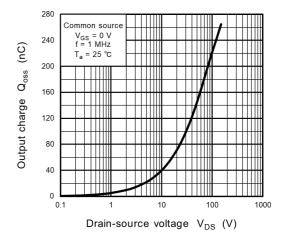


Fig. 8.12 Q_{oss} - V_{DS}



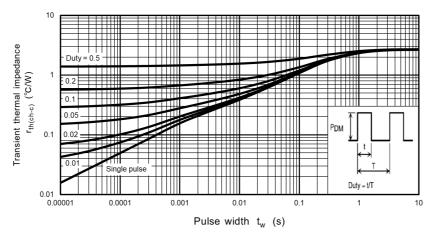
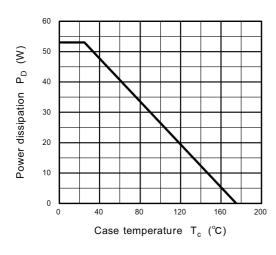


Fig. 8.13 r_{th} - t_w (Guaranteed Maximum)



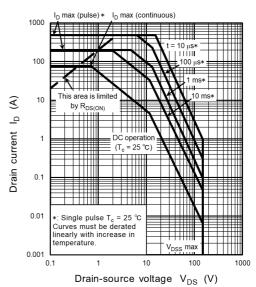


Fig. 8.14 P_D - T_c (Guaranteed Maximum)

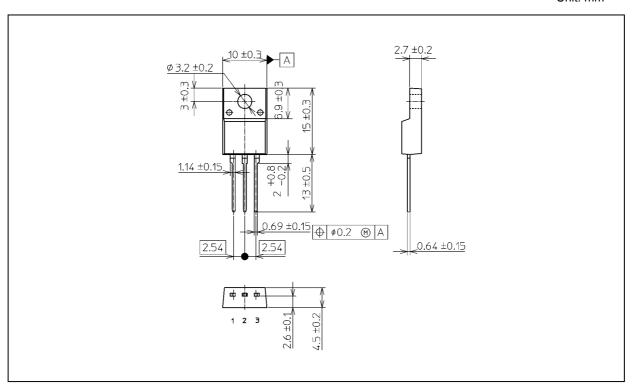
Fig. 8.15 Safe Operating Area (Guaranteed Maximum)

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 1.56 g (typ.)

Package Name(s)	
TOSHIBA: 2-10U1S	
Nickname: TO-220SIS	



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